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Inclosure Material:

Metal

Overall Length:

Between 1.188 inches and 1.252 inches

Overall Height:

Between 0.610 inches and 0.840 inches

Overall Width:

0.700 inches

End Application:

1430-01-215-7255

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-275.0 collector to base voltage/static/emitter open and -225.0 collector to emitter voltage/static/base open and -6.0 emitter to base

voltage, static, collector open

Current Rating Per Characteristic:

Between -1.00 amperes source cutoff current and -2.00 amperes source cutoff current

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

18876-11437179 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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